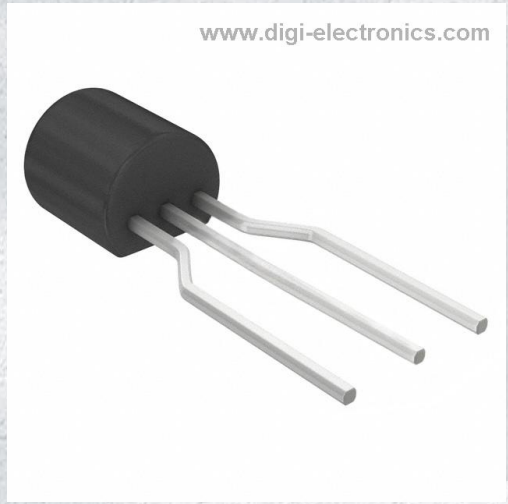
BS107ARL1 Datasheet



DiGi Electronics Part Number	BS107ARL1-DG
Manufacturer	onsemi
Manufacturer Product Number	BS107ARL1
Description	MOSFET N-CH 200V 250MA TO92-3
Detailed Description	N-Channel 200 V 250mA (Ta) 350mW (Ta) Through Hole TO-92 (TO-226)

https://www.DiGi-Electronics.com

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BS107ARL1	onsemi
Series:	Product Status:
-	Obsolete
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
200 V	250mA (Ta)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	6.4Ohm @ 250mA, 10V
Vgs(th) (Max) @ Id:	Vgs (Max):
3V @ 1mA	±20V
Input Capacitance (Ciss) (Max) @ Vds:	FET Feature:
60 pF @ 25 V	-
Power Dissipation (Max):	Operating Temperature:
350mW (Ta)	-55°C ~ 150°C (TJ)
Mounting Type:	Supplier Device Package:
Through Hole	TO-92 (TO-226)
Package / Case:	Base Product Number:
TO-226-3, TO-92-3 Long Body (Formed Leads)	BS107

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
RoHS non-compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	

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BS107A

Small Signal MOSFET

250 mA, 200 V, N−Channel TO−92

Features

- AEC−Q101 Qualified and PPAP Capable
- This is a Pb−Free Device*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain−Source Voltage	V_{DS}	200	Vdc
Gate−Source Voltage − Continuous − Non−repetitive ($t_p \le 50$ μs)	 V_{GS} V_{GSM}	 ±20 ±30	 Vdc Vpk
Drain Current Continuous (Note 1) Pulsed (Note 2)	 I_D I_{DM}	 250 500	mAdc
Total Device Dissipation @ T_A = 25°C Derate above 25°C	P_D	350	mW
Operating and Storage Junction Temperature Range	T_J, T_{stg}	−55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The Power Dissipation of the package may result in a lower continuous drain current.
2. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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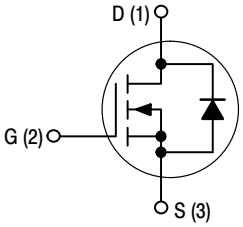
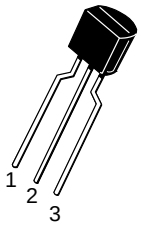
http://onsemi.com

250 mAMPS, 200 VOLTS

$R_{DS(on)}$ = 6.4 Ω

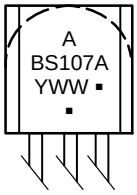


N−Channel



TO−92
CASE 29−11
STYLE 30

MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb−Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping
BS107ARL1G	TO−92 (Pb−Free)	2000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

BS107A

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Zero−Gate−Voltage Drain Current (V_{DS} = 130 Vdc, V_{GS} = 0)	I_{DSS}	−	−	30	nAdc
Drain−Source Breakdown Voltage (V_{GS} = 0, I_D = 100 μAdc)	$V_{(BR)DSX}$	200	−	−	Vdc
Gate Reverse Current (V_{GS} = 15 Vdc, V_{DS} = 0)	I_{GSS}	−	0.01	10	nAdc
ON CHARACTERISTICS (Note 3)					
Gate Threshold Voltage (I_D = 1.0 mAdc, V_{DS} = V_{GS})	$V_{GS(Th)}$	1.0	−	3.0	Vdc
Static Drain−Source On Resistance	$r_{DS(on)}$				Ω
BS107 (V_{GS} = 2.6 Vdc, I_D = 20 mAdc)		−	−	28	
(V_{GS} = 10 Vdc, I_D = 200 mAdc)		−	−	14	
BS107A (V_{GS} = 10 Vdc)					
(I_D = 100 mAdc)		−	4.5	6.0	
(I_D = 250 mAdc)		−	4.8	6.4	
SMALL−SIGNAL CHARACTERISTICS					
Input Capacitance (V_{DS} = 25 Vdc, V_{GS} = 0, f = 1.0 MHz)	C_{iss}	−	60	−	pF
Reverse Transfer Capacitance (V_{DS} = 25 Vdc, V_{GS} = 0, f = 1.0 MHz)	C_{rss}	−	6.0	−	pF
Output Capacitance (V_{DS} = 25 Vdc, V_{GS} = 0, f = 1.0 MHz)	C_{oss}	−	30	−	pF
Forward Transconductance (V_{DS} = 25 Vdc, I_D = 250 mAdc)	g_{fs}	200	400	−	mmhos
SWITCHING CHARACTERISTICS					
Turn−On Time	t_{on}	−	6.0	15	ns
Turn−Off Time	t_{off}	−	12	15	ns

3. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

RESISTIVE SWITCHING

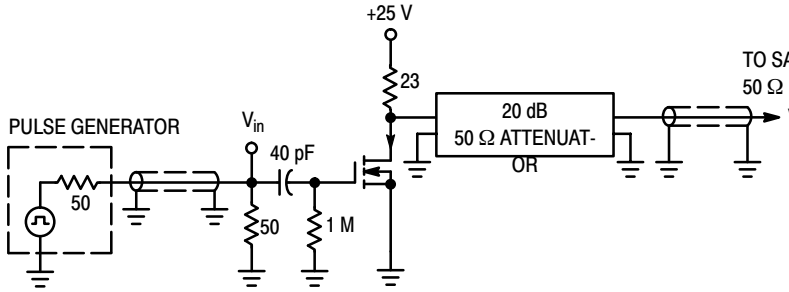


Figure 1. Switching Test Circuit

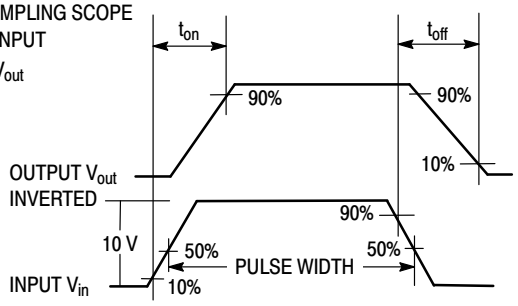


Figure 2. Switching Waveforms

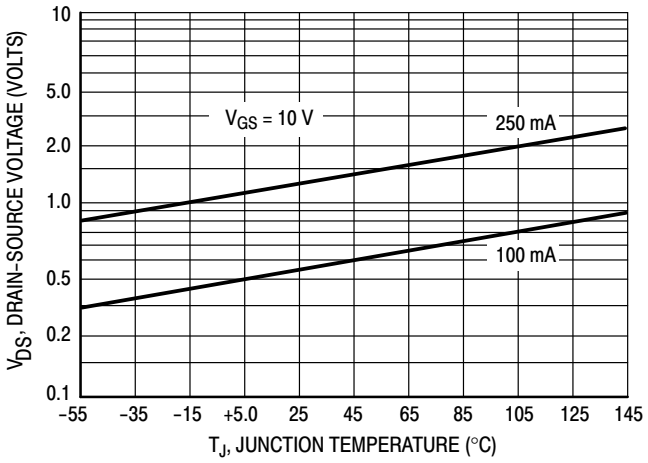


Figure 3. On Voltage versus Temperature

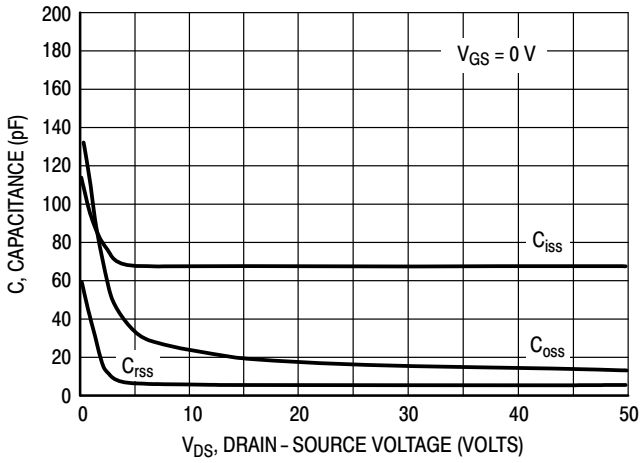


Figure 4. Capacitance Variation

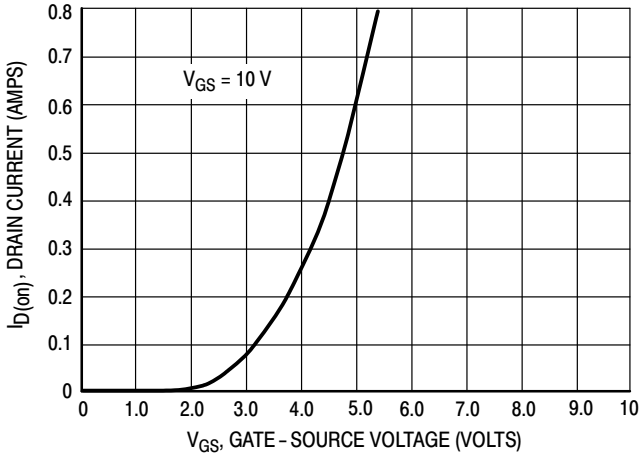


Figure 5. Transfer Characteristic

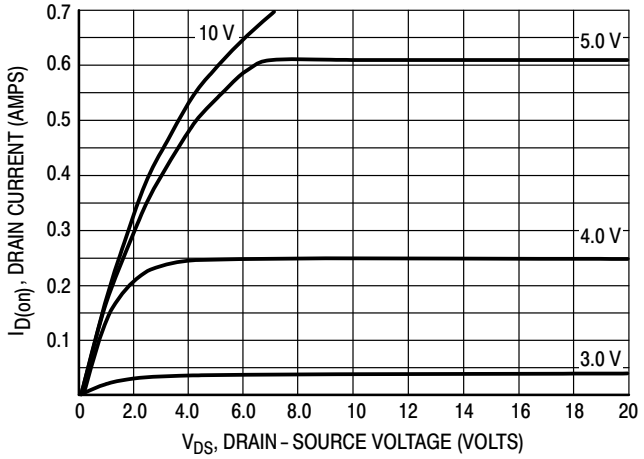


Figure 6. Output Characteristic

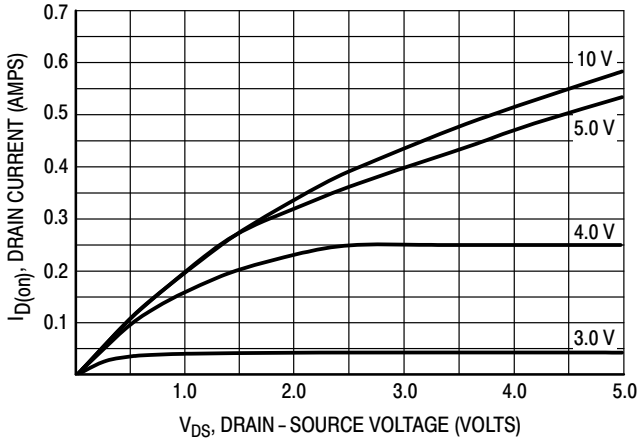
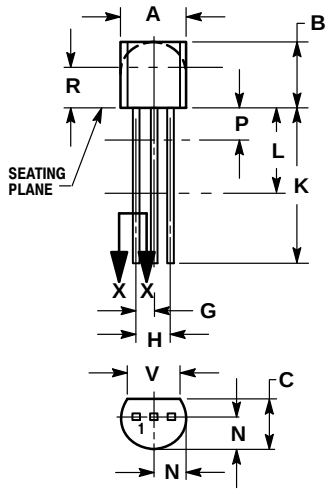


Figure 7. Saturation Characteristic

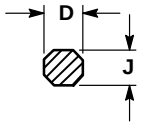
BS107A

PACKAGE DIMENSIONS

TO−92 (TO−226)
CASE 29−11
ISSUE AM



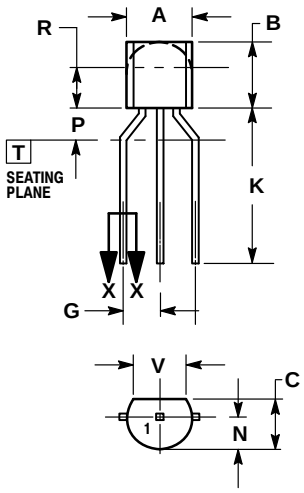
STRAIGHT LEAD
BULK PACK



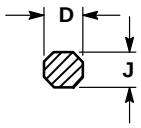
SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---



BENT LEAD
TAPE & REEL
AMMO PACK



SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS	
DIM	MIN	MAX
A	4.45	5.20
B	4.32	5.33
C	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	---
N	2.04	2.66
P	1.50	4.00
R	2.93	---
V	3.43	---

STYLE 30:
PIN 1. DRAIN
2. GATE
3. SOURCE

PUBLICATION ORDERING INFORMATION

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BS107/D

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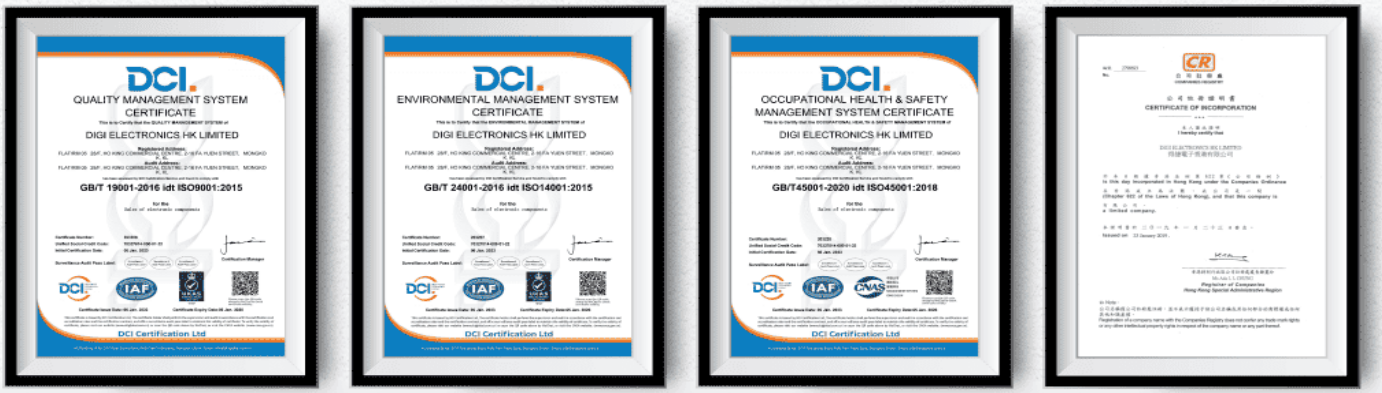

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